









	<h2 style="color: red;">FQB12N60CTM</h2>
	<p>Hersteller-Teilenummer: FQB12N60CTM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 12A D2PAK</p> <p>Datenblätter:  FQB12N60CTM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 37363 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB12N60CTM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 12A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	37363 pcs Stock
detaillierte Beschreibung	N-Channel 600V 12A (Tc) 3.13W (Ta), 225W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 225W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	650 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	63nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2290pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)














































FQB12N60CTM ist neu im Original, Suche FQB12N60CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB12N60CTM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB12N60CTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB12N60TM_AM002 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 10.5A D2PAK</p>	 <p>FQB12P10TM Fairchild/ON Semiconductor MOSFET P-CH 100V 11.5A D2PAK</p>	 <p>FQB12N50TM_AM002 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 12.1A D2PAK</p>	 <p>FQB12N50TM_AM002 Fairchild/ON Semiconductor MOSFET N-CH 500V 12.1A D2PAK</p>
 <p>FQB12N60CTM Fairchild/ON Semiconductor MOSFET N-CH 600V 12A D2PAK</p>	 <p>FQB12N60 FAIRCHI FQB12N60 FAIRCHI</p>	 <p>FQB12N60TM Fairchild/ON Semiconductor FQB12N60TM FAIRCHILD</p>	 <p>FQB12N60TM_AM002 Fairchild/ON Semiconductor MOSFET N-CH 600V 10.5A D2PAK</p>

heiße Teile

Mehr

 FQB10N20LTM	 FQB10N20LTM	 FQB10N20TM	 FQB10N20TM	 FQB10N50CF
 FQB10N50CFTM	 FQB10N50CFTM_WS	 FQB10N60C	 FQB10N60CTM	 FQB10N60CTM
 FQB11N40	 FQB11N40C	 FQB11N40CTM	 FQB11N40CTM	 FQB11N60FTM
 FQB11N60TM	 FQB11P06	 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI
 FQB12N50TM	 FQB12N50TM_AM002	 FQB12N50TM_AM002	 FQB12N60	 FQB12N60C
 FQB12N60CTM	 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10
 FQB12P10TM	 FQB12P10TM	 FQB12P20	 FQB12P20TM	 FQB12P20TM
 FQB13N06L	 FQB13N10	 FQB13N10L	 FQB13N50	 FQB13N50CTM
 FQB13N50CTM	 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM
 FQB16N25TM	 FQB17P06	 FQB17P10	 FQB17P10TM	 FQB17P10TM

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